

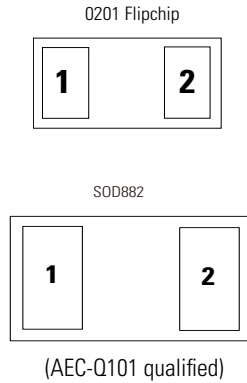
SP3022 Series 0.35pF 20kV Bidirectional Discrete TVS



Description

The SP3022 includes back-to-back TVS diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the international standard IEC 61000-4-2, without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present and the low loading capacitance makes it ideal for protecting high speed data lines such as HDMI, USB2.0, USB3.0 and eSATA.

Pinout



Features

- Lead-Free and RoHS-Compliant
- ESD; $\pm 20\text{kV}$ contact discharge; $\pm 30\text{kV}$ air discharge per IEC 61000-4-2 EFT; 40A, 5/50ns per IEC 61000-4-4 Lightning, 3A, 8/20 μs per IEC 61000-4-5 2nd Edition
- Low capacitance of 0.35pF @ $V_R=0\text{V}$ (TYP)
- Low leakage current of 100nA at 5.3V (MAX)
- Space efficient 0201 and SOD882 footprint
- Extremely low dynamic resistance (0.7 Ω TYP)
- AEC-Q101 qualified (SOD882 package)

Functional Block Diagram



Applications

- USB 3.0/USB 2.0/MHL
- MIPI Camera and Display
- HDMI 2.0, DisplayPort 1.3, eSATA
- Set Top Boxes, Game Consoles
- Smart Phones
- External Storage
- Ultrabooks, Notebooks
- Tablets, eReaders
- Automotive Electronics

Additional Information



Datasheet



Resources



Samples

Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{PK}	Peak Pulse Power ($t_p=8/20\mu s$)	20	W
I_{PP}	Peak Current ($t_p=8/20\mu s$)	3.0	A
T_{OP}	Operating Temperature	-40 to 125	°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics ($T_{OP}=25^\circ C$)

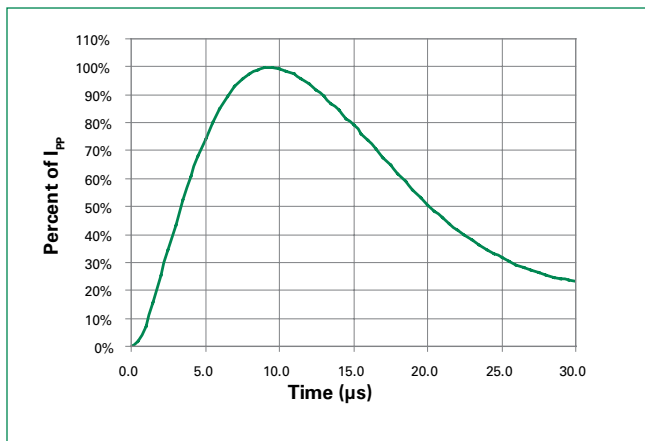
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}				5.3	V
Reverse Breakdown Voltage	V_{BR}	$I_R=1mA$	6.8	7.8	9.1	V
Reverse Leakage Current	I_{LEAK}	$V_R=5.3V$		<10	100	nA
Clamp Voltage ¹	V_C	$I_{PP}=1A, t_p=8/20\mu s, Fwd$			12.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p=100ns, I/O$ to GND		0.7		Ω
ESD Withstand Voltage ¹	V_{ESD}	IEC 61000-4-2 (Contact)	± 20			kV
		IEC 61000-4-2 (Air)	± 30			kV
Diode Capacitance ¹	C_D	Reverse Bias=0V		0.35	0.5	pF

Note:

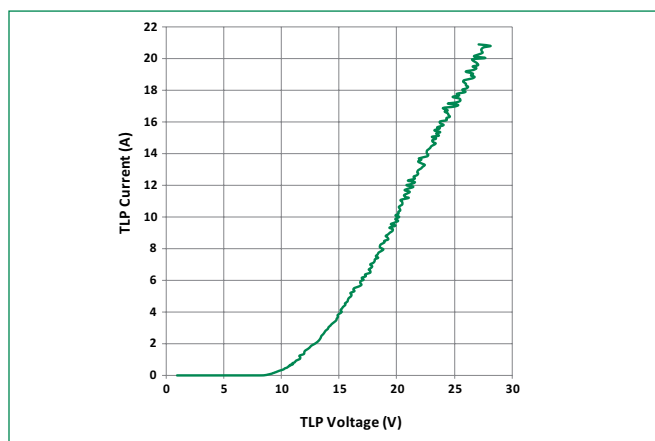
¹ Parameter is guaranteed by design and/or component characterization.

² Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

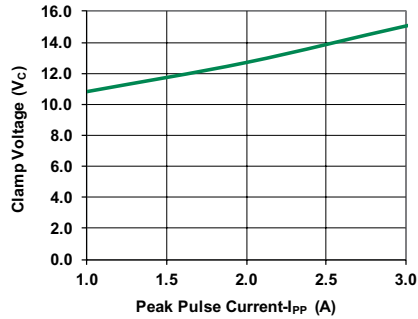
8/20 Pulse Waveform



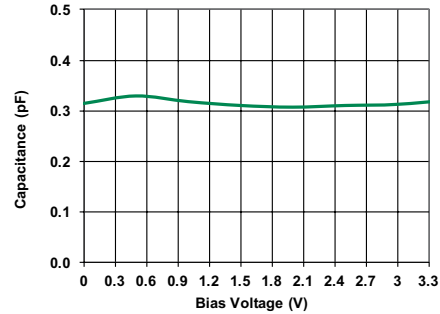
Transmission Line Pulsing (TLP) Plot



Clamping Voltage vs I_{PP}

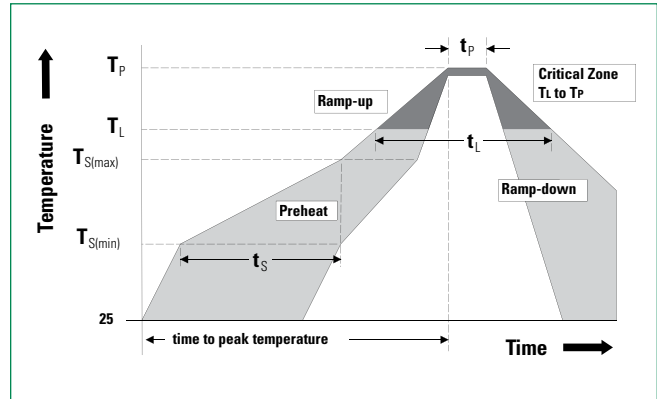


Capacitance vs. Reverse Bias



Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Product Characteristics of 0201 Flipchip

Lead Plating	Sn
Lead Material	Copper
Substrate material	Silicon
Body Material	Silicon

Product Characteristics of SOD882

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Substrate material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0.

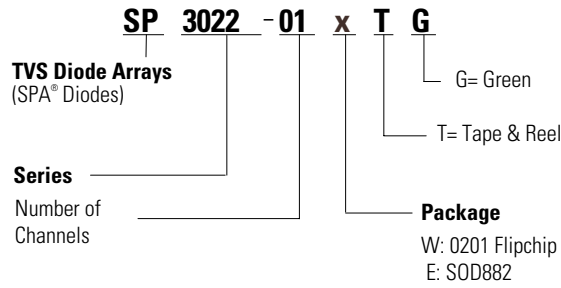
Notes :

1. All dimensions are in millimeters
2. Dimensions include solder plating.
3. Dimensions are exclusive of mold flash & metal burr.
4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
5. Package surface matte finish VDI 11-13.

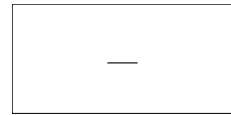
Ordering Information

Part Number	Package	Min. Order Qty.
SP3022-01WTG	0201 Flipchip	10000
SP3022-01ETG	SOD882	10000

Part Numbering System



Part Marking System

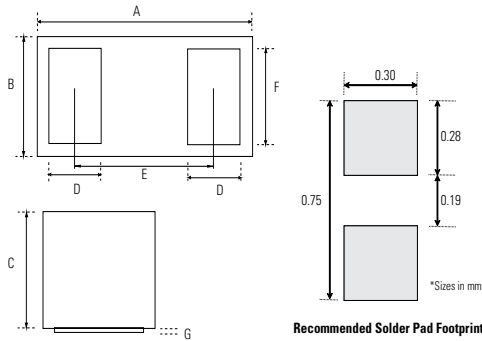


SP3022-01WTG



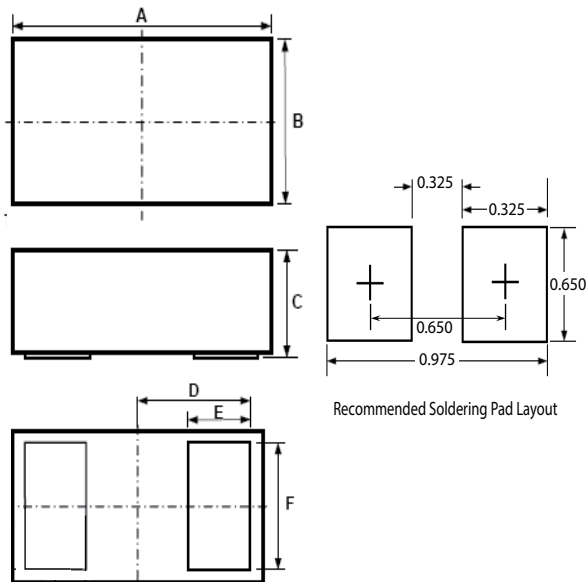
SP3022-01ETG

Package Dimensions — 0201 Flipchip



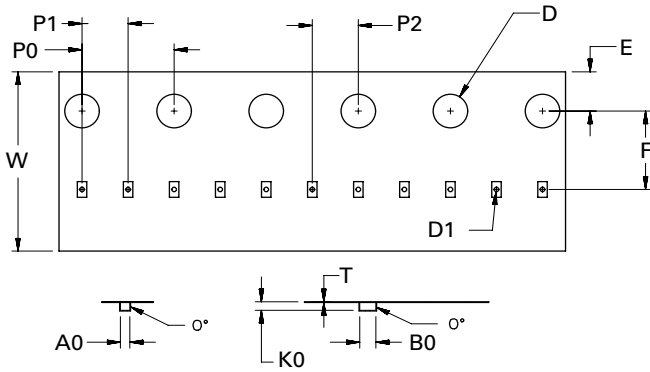
Symbol	0201 Flipchip					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.605	0.630	0.655	0.0238	0.0248	0.0258
B	0.305	0.330	0.355	0.0120	0.0130	0.0140
C	0.265	0.290	0.315	0.0104	0.0114	0.0124
D	0.115	0.120	0.125	0.0045	0.0047	0.0049
E	-	0.4	-	-	0.0157	-
F	0.215	0.220	0.225	0.0085	0.0087	0.0089
G	0.008	0.011	0.014	0.0003	0.0004	0.0006

Package Dimensions — SOD882



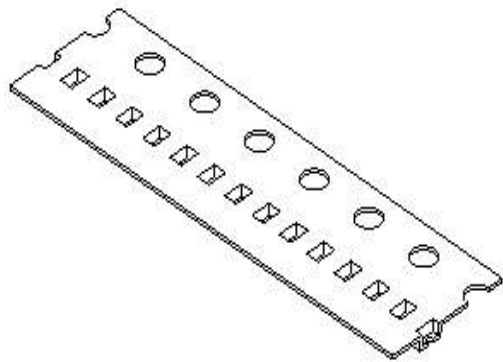
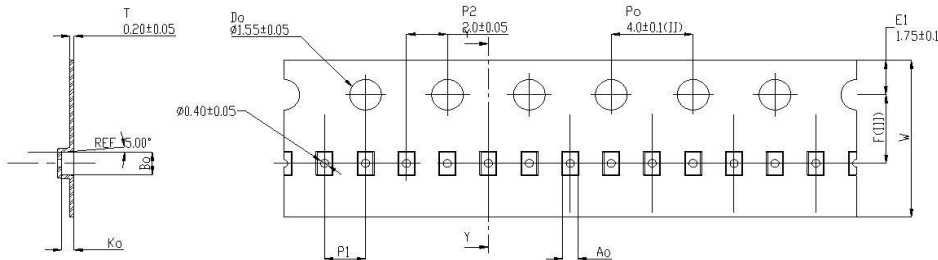
Symbol	Package	SOD882					
	JEDEC	MO-236			Inches		
		Min	Typ	Max	Min	Typ	Max
A		0.95	1.00	1.10	0.035	0.039	0.043
B		0.50	0.60	0.70	0.020	0.024	0.028
C		0.40	0.50	0.60	0.016	0.020	0.024
D			0.45			0.018	
E		0.20	0.25	0.35	0.008	0.010	0.012
F		0.45	0.50	0.55	0.018	0.020	0.022

Embossed Carrier Tape & Reel Specification – 0201 Flipchip



Symbol	Millimeters
A0	0.41+/-0.03
B0	0.70+/-0.03
D	ø 1.50 + 0.10
D1	ø 0.20 +/- 0.05
E	1.75+/-0.10
F	3.50+/-0.05
K0	0.38+/-0.03
P0	4.00+/-0.10
P1	2.00+/-0.05
P2	2.00+/-0.05
W	8.00 + 0.30 -0.10
T	0.23+/-0.02

Embossed Carrier Tape & Reel Specification – SOD882



Symbol	Millimeters
A0	0.70+/-0.045
B0	1.10+/-0.045
K0	0.65+/-0.045
F	3.50+/-0.05
P1	2.00+/-0.10
W	8.00 + 0.30 -0.10